

Ref #	Hits	Search Query	DBs	Default Operator	Plurals	Time Stamp
L1	619	((ultraviolet or uv or ultra-violet) with (detector or sensor)) and (p adj type or p-type or n adj type or n-type)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/08/19 16:51
L2	514	((ultraviolet or uv or ultra-violet) with (detector or sensor)) and (p adj type or p-type or n adj type or n-type)) and (envelop or well)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/08/19 16:52
L3	455	((ultraviolet or uv or ultra-violet) with (detector or sensor)) and (p adj type or p-type or n adj type or n-type)) and (envelop or well) and semiconductor	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/08/19 16:52
L4	99	((ultraviolet or uv or ultra-violet) with (detector or sensor)) and (p adj type or p-type or n adj type or n-type)) and (envelop or well) and semiconductor) and circular	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/08/19 17:01
L5	26	((ultraviolet or uv or ultra-violet) with (detector or sensor)) and (p adj type or p-type or n adj type or n-type)) and (envelop or well) and semiconductor) and circular) and GaN	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/08/19 17:02
L6	724	((p adj type or p-type or n adj type or n-type) and (envelop or well) and semiconductor) and circular) and GaN	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/08/19 17:02
L7	315	((p adj type or p-type or n adj type or n-type) and (envelop or well) and semiconductor) and circular) and GaN) and ohmic	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/08/19 17:14
L8	14	((p adj type or p-type or n adj type or n-type) and (envelop or well) and semiconductor) and circular) and GaN) and ohmic) and "250"/\$	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/08/19 17:18
L9	230	((p adj type or p-type or n adj type or n-type) and (envelop or well) and semiconductor) and circular) and GaN) and ohmic) and "257"/\$	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/08/19 17:15
L10	1	((p adj type or p-type or n adj type or n-type) and (envelop or well) and semiconductor) and circular) and GaN) and ohmic) and 257/463	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/08/19 17:15

L11	118	(((p adj type or p-type or n adj type or n-type) and (envelop or well) and semiconductor) and circular) and GaN) and ohmic) and "438"/\$	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/08/19 17:15
L12	4	(((p adj type or p-type or n adj type or n-type) and (envelop or well) and semiconductor) and circular) and GaN) and ohmic) and 438/93	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/08/19 17:15
L13	1	1 and 8	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/08/19 17:19
L14	6	1 and 11	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/08/19 17:19